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# PM50B5L1C060

FLAT-BASE TYPE  
INSULATED PACKAGE

## PM50B5L1C060



### FEATURE

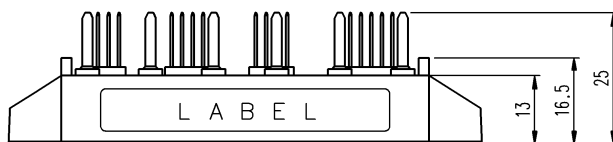
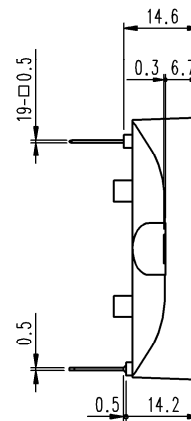
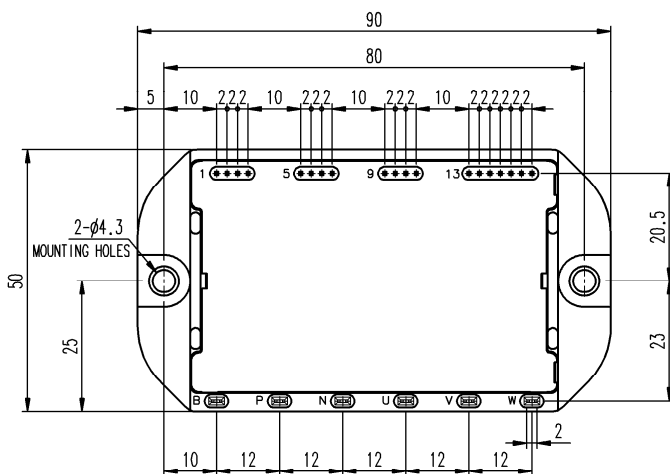
- a) Adopting new 5th generation Full-Gate CSTBT™ chip
  - b) Error output signal is possible from all each protection upper and lower IGBT.
  - c) The mounting surface is 90mm×50mm about 30% less than B5LA type
- Monolithic gate drive & protection logic
  - Detection, protection & status indication circuits for, short-circuit, over-temperature & under-voltage.

## APPLICATION

Photo voltaic power conditioner

### PACKAGE OUTLINES

Dimensions in mm



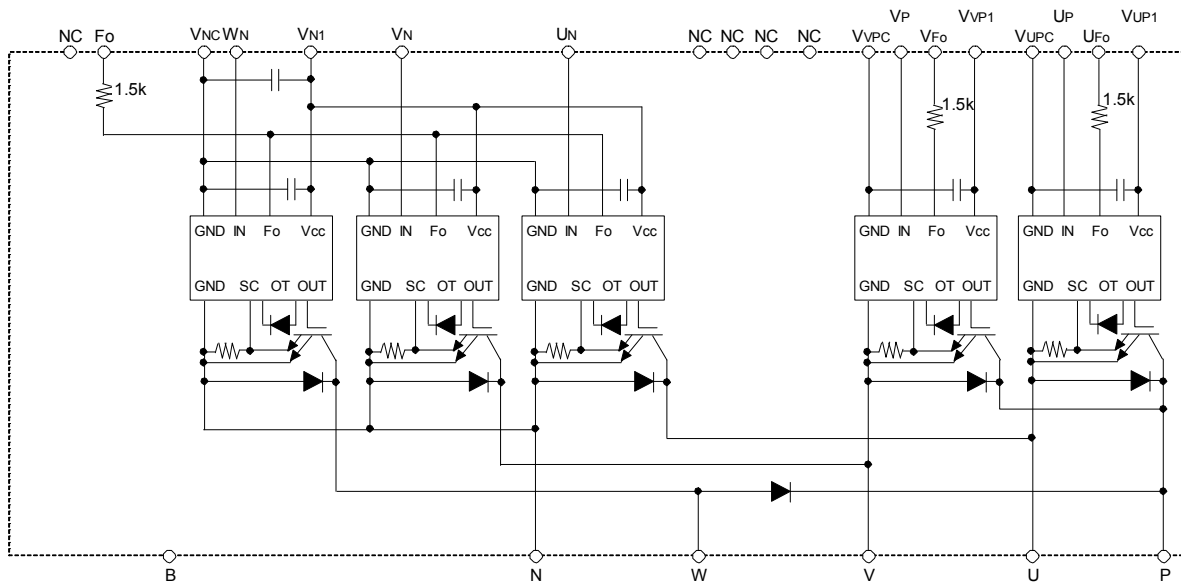
### Terminal code

1. VUPC	8. VVP1	15. NC
2. UFo	9. NC	16. UN
3. UP	10. NC	17. VN
4. VUP1	11. NC	18. WN
5. VVPC	12. NC	19. Fo
6. VFo	13. VNC	
7. VP	14. VN1	

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INTERNAL FUNCTIONS BLOCK DIAGRAM



MAXIMUM RATINGS ( $T_j = 25^\circ\text{C}$ , unless otherwise noted)

INVERTER PART

Symbol	Parameter	Conditions	Ratings	Unit
$V_{CES}$	Collector-Emitter Voltage	$V_D=15\text{V}$ , $V_{CIN}=15\text{V}$	600	V
$I_C$	Collector Current	$T_c=25^\circ\text{C}$	50	A
$I_{CRM}$		Pulse	100	
$P_{tot}$	Total Power Dissipation	$T_c=25^\circ\text{C}$	168	W
$I_E$	Emitter Current	$T_c=25^\circ\text{C}$	50	A
$I_{ERM}$	(Free wheeling Diode Forward current)	Pulse	100	
$T_j$	Junction Temperature		-20 ~ +150	$^\circ\text{C}$

\*:  $T_c$  measurement point is just under the chip.

CONVERTER PART

Symbol	Parameter	Conditions	Ratings	Unit
$V_{CES}$	Collector-Emitter Voltage	$V_D=15\text{V}$ , $V_{CIN}=15\text{V}$	600	V
$I_C$	Collector Current	$T_c=25^\circ\text{C}$	50	A
$I_{CRM}$		Pulse	100	
$P_{tot}$	Total Power Dissipation	$T_c=25^\circ\text{C}$	168	W
$I_E$	Emitter Current	$T_c=25^\circ\text{C}$	50	A
$I_{ERM}$	(Free wheeling Diode Forward current)	Pulse	100	
$I_F$	Di Forward Current	$T_c=25^\circ\text{C}$	50	A
$V_{R(DC)}$	Di Rated DC Reverse Voltage	$T_c=25^\circ\text{C}$	600	V
$T_j$	Junction Temperature		-20 ~ +150	$^\circ\text{C}$

\*:  $T_c$  measurement point is just under the chip.

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**CONTROL PART**

Symbol	Parameter	Conditions	Ratings	Unit
$V_D$	Supply Voltage	Applied between : $V_{UP1}-V_{UPC}, V_{VP1}-V_{VPC}, V_{N1}-V_{NC}$	20	V
$V_{CIN}$	Input Voltage	Applied between : $UP-V_{UPC}, VP-V_{VPC}, UN \cdot VN \cdot WN -V_{NC}$	20	V
$V_{FO}$	Fault Output Supply Voltage	Applied between : $UFo-V_{UPC}, VFo-V_{VPC}, Fo-V_{NC}$	20	V
$I_{FO}$	Fault Output Current	Sink current at $UFo, VFo, Fo$ terminals	20	mA

**TOTAL SYSTEM**

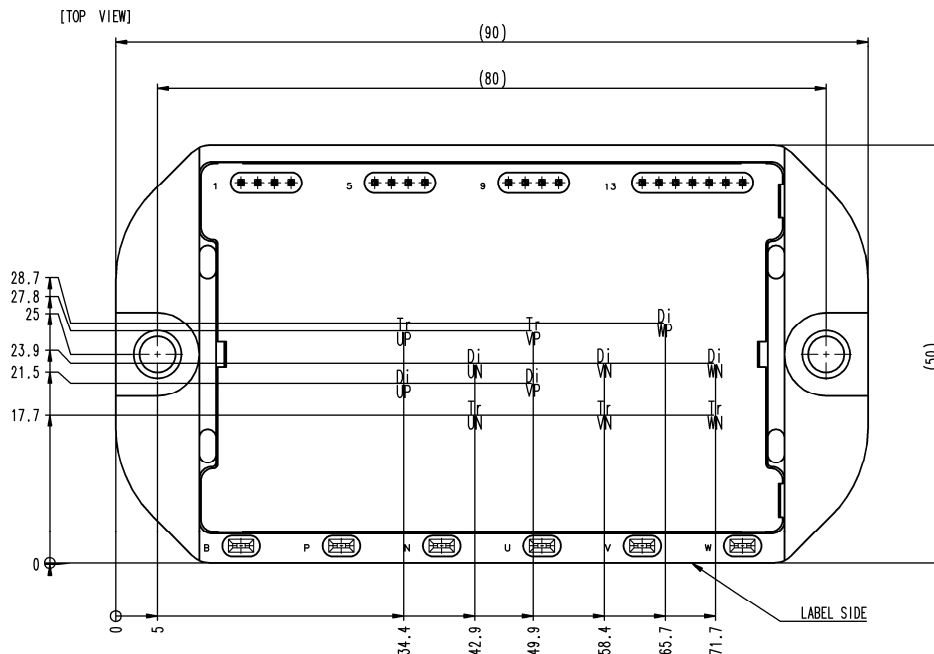
Symbol	Parameter	Conditions	Ratings	Unit
$V_{CC(PROT)}$	Supply Voltage Protected by SC	$V_D = 13.5V \sim 16.5V$ Inverter Part, $T_j = +125^\circ C$ Start	450	V
$V_{CC(surge)}$	Supply Voltage (Surge)	Applied between : P-N, Surge value	500	V
$T_{stg}$	Storage Temperature		-40 ~ +125	$^\circ C$
$V_{isol}$	Isolation Voltage	60Hz, Sinusoidal, Charged part to Base plate, AC 1min, RMS	2500	V

\*:  $T_c$  measurement point is just under the chip.

**THERMAL RESISTANCE**

Symbol	Parameter	Conditions	Limits			Unit
			Min.	Typ.	Max.	
$R_{th(j-c)Q}$	Thermal Resistance	Inverter, IGBT (per 1 element) (Note.1)	-	-	0.74	K/W
$R_{th(j-c)D}$		Inverter, FWDi (per 1 element) (Note.1)	-	-	1.28	
$R_{th(j-c)Q}$		Converter, IGBT (per 1 element) (Note.1)	-	-	0.74	
$R_{th(j-c)D}$		Converter, FWDi (per 1 element) (Note.1)	-	-	1.28	
$R_{th(j-c)D}$		Converter, Di (per 1 element) (Note.1)	-	-	1.28	
$R_{th(c-s)}$	Contact Thermal Resistance	Case to heat sink, (per 1 module) Thermal grease applied (Note.1)	-	0.06	-	

Note.1: If you use this value,  $R_{th(s-a)}$  should be measured just under the chips.



ELECTRICAL CHARACTERISTICS (T<sub>j</sub> = 25°C, unless otherwise noted)

## INVERTER PART

Symbol	Parameter	Conditions	Limits			Unit	
			Min.	Typ.	Max.		
V <sub>CEsat</sub>	Collector-Emitter Saturation Voltage	V <sub>D</sub> =15V, I <sub>C</sub> =50A V <sub>CIN</sub> =0V, Pulsed (Fig. 1)	T <sub>j</sub> =25°C	-	2.2	2.7	V
			T <sub>j</sub> =125°C	-	2.2	2.7	
V <sub>EC</sub>	Emitter-Collector Voltage	I <sub>E</sub> =50A, V <sub>D</sub> =15V, V <sub>CIN</sub> =15V (Fig. 2)	-	2.4	3.3	V	
t <sub>on</sub>	Switching Time	V <sub>D</sub> =15V, V <sub>CIN</sub> =0V↔15V V <sub>CC</sub> =300V, I <sub>C</sub> =50A T <sub>j</sub> =125°C Inductive Load (Fig. 3,4)		0.1	0.5	1.2	μs
t <sub>rr</sub>				-	0.1	0.2	
t <sub>c(on)</sub>				-	0.15	0.3	
t <sub>off</sub>				-	1.1	2.0	
t <sub>c(off)</sub>				-	0.2	0.4	
I <sub>CES</sub>	Collector-Emitter Cut-off Current	V <sub>CE</sub> =V <sub>CES</sub> , V <sub>D</sub> =15V, V <sub>CIN</sub> =15V (Fig. 5)	T <sub>j</sub> =25°C	-	-	1	mA
			T <sub>j</sub> =125°C	-	-	10	

## CONVERTER PART

Symbol	Parameter	Conditions	Limits			Unit	
			Min.	Typ.	Max.		
V <sub>CEsat</sub>	Collector-Emitter Saturation Voltage	V <sub>D</sub> =15V, I <sub>C</sub> =50A V <sub>CIN</sub> =0V, Pulsed (Fig. 1)	T <sub>j</sub> =25°C	-	2.2	2.7	V
			T <sub>j</sub> =125°C	-	2.2	2.7	
V <sub>EC</sub>	Emitter-Collector Voltage	I <sub>E</sub> =50A, V <sub>D</sub> =15V, V <sub>CIN</sub> =15V (Fig. 2)	-	2.4	3.3	V	
V <sub>FM</sub>	Di Forward Voltage	I <sub>F</sub> =50A	-	2.4	3.3	V	
t <sub>on</sub>	Switching Time	V <sub>D</sub> =15V, V <sub>CIN</sub> =0V↔15V V <sub>CC</sub> =300V, I <sub>C</sub> =50A T <sub>j</sub> =125°C Inductive Load (Fig. 3,4)		0.1	0.5	1.2	μs
t <sub>rr</sub>				-	0.1	0.2	
t <sub>c(on)</sub>				-	0.15	0.3	
t <sub>off</sub>				-	1.1	2.0	
t <sub>c(off)</sub>				-	0.2	0.4	
I <sub>CES</sub>	Collector-Emitter Cut-off Current	V <sub>CE</sub> =V <sub>CES</sub> , V <sub>D</sub> =15V, V <sub>CIN</sub> =15V (Fig. 5)	T <sub>j</sub> =25°C	-	-	1	mA
			T <sub>j</sub> =125°C	-	-	10	

## CONTROL PART

Symbol	Parameter	Conditions	Limits			Unit	
			Min.	Typ.	Max.		
I <sub>D</sub>	Circuit Current	V <sub>D</sub> =15V, V <sub>CIN</sub> =15V	V <sub>N1</sub> -V <sub>NC</sub>	-	6.5	12	mA
			V <sub>P1</sub> -V <sub>PC</sub>	-	1.6	4.0	
V <sub>th(ON)</sub>	Input ON Threshold Voltage	Applied between : UP-V <sub>UPC</sub> , VP-V <sub>VPC</sub> , UN·VN·WN -V <sub>NC</sub>		1.2	1.5	1.8	V
V <sub>th(OFF)</sub>	Input OFF Threshold Voltage			1.7	2.0	2.3	
SC	Short Circuit Trip Level	-20≤T <sub>j</sub> ≤125°C, V <sub>D</sub> =15V (Fig. 3, 6)	75	-	-	A	
t <sub>off(SC)</sub>	Short Circuit Current Delay Time	V <sub>D</sub> =15V (Fig. 3, 6)	-	0.2	-	μs	
OT	Over Temperature Protection	Detect Temperature of IGBT chip	Trip level	135	-	-	°C
OT <sub>(hys)</sub>			Hysteresis	-	20	-	
UV <sub>t</sub>	Supply Circuit Under-Voltage Protection	-20≤T <sub>j</sub> ≤125°C	Trip level	11.5	12.0	12.5	V
UV <sub>r</sub>			Reset level	-	12.5	-	
I <sub>FO(H)</sub>	Fault Output Current	V <sub>D</sub> =15V, V <sub>FO</sub> =15V (Note.2)		-	-	0.01	mA
I <sub>FO(L)</sub>				-	10	15	
t <sub>FO</sub>	Fault Output Pulse Width	V <sub>D</sub> =15V (Note.2)	1.0	1.8	-	ms	

Note.2: Fault output is given only when the internal SC, OT & UV protections schemes of either upper or lower arm device operate to protect it.

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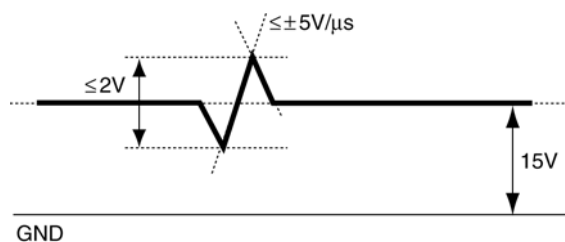
## MECHANICAL RATINGS AND CHARACTERISTICS

Symbol	Parameter	Conditions	Limits			Unit
			Min.	Typ.	Max.	
$M_s$	Mounting Torque	Mounting part screw : M4	1.4	1.65	1.9	N·m
m	Weight	-	-	135	-	g

## RECOMMENDED CONDITIONS FOR USE

Symbol	Parameter	Conditions	Recommended value	Unit
$V_{CC}$	Supply Voltage	Applied across P-N terminals	$\leq 450$	V
$V_D$	Control Supply Voltage	Applied between : $V_{UP1}-V_{UPC}$ , $V_{VP1}-V_{VPC}$ ; $V_{N1}-V_{NC}$ (Note.3)	$15.0 \pm 1.5$	V
$V_{CIN(ON)}$	Input ON Voltage	Applied between : $UP-V_{UPC}$ , $VP-V_{VPC}$ , $UN \cdot VN \cdot WN -V_{NC}$	$\leq 0.8$	V
$V_{CIN(OFF)}$	Input OFF Voltage		$\geq 9.0$	
$f_{PWM}$	PWM Input Frequency	Using Application Circuit of Fig. 8	$\leq 20$	kHz
$t_{dead}$	Arm Shoot-through Blocking Time	For IPM's each input signals (Fig. 7)	$\geq 2.0$	$\mu s$
$I_o$	Module Operating Current	RMS	$\leq 20$	A

Note.3: With ripple satisfying the following conditions:  $dv/dt$  swing  $\leq \pm 5V/\mu s$ , Variation  $\leq 2V$  peak to peak





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## PRECAUTIONS FOR TESTING

1. Before applying any control supply voltage ( $V_D$ ), the input terminals should be pulled up by resistors, etc. to their corresponding supply voltage and each input signal should be kept off state.  
After this, the specified ON and OFF level setting for each input signal should be done.
2. When performing "SC" tests, the turn-off surge voltage spike at the corresponding protection operation should not be allowed to rise above  $V_{CES}$  rating of the device.  
(These test should not be done by using a curve tracer or its equivalent.)

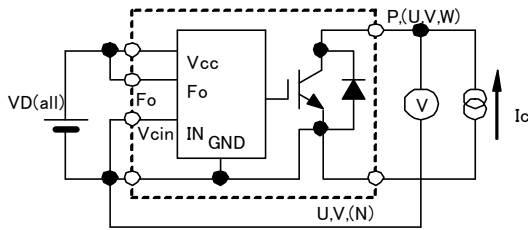


Fig. 1  $V_{CESat}$  Test

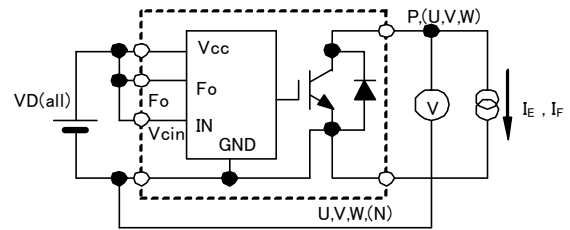


Fig. 2  $V_{EC}$ ,  $V_{FM}$  Test

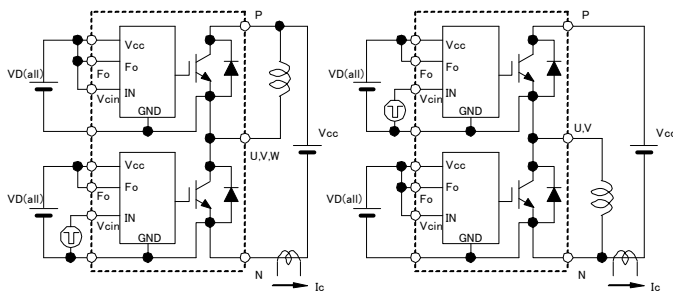


Fig. 3 Switching time and SC test circuit

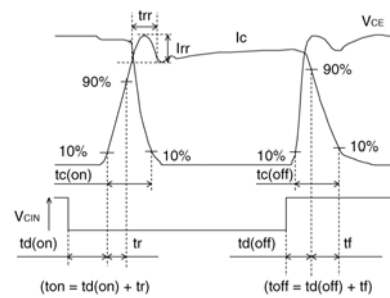


Fig. 4 Switching time test waveform

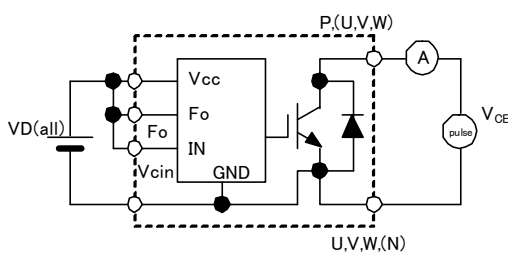


Fig. 5  $I_{CES}$  Test

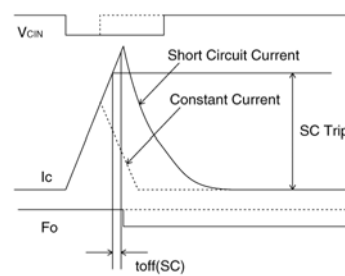
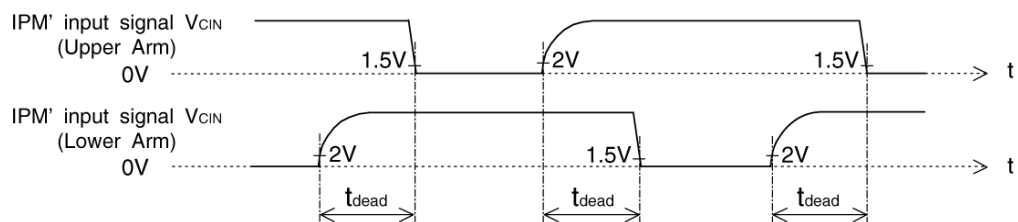


Fig. 6 SC test waveform



1.5V: Input on threshold voltage  $V_{th(on)}$  typical value, 2V: Input off threshold voltage  $V_{th(off)}$  typical value

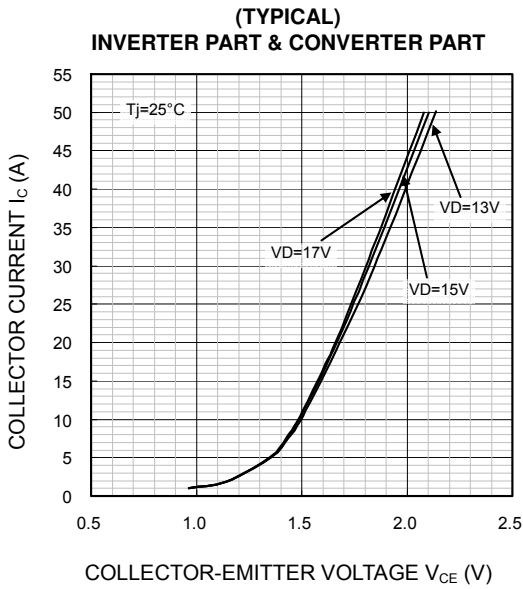
Fig. 7 Dead time measurement point example



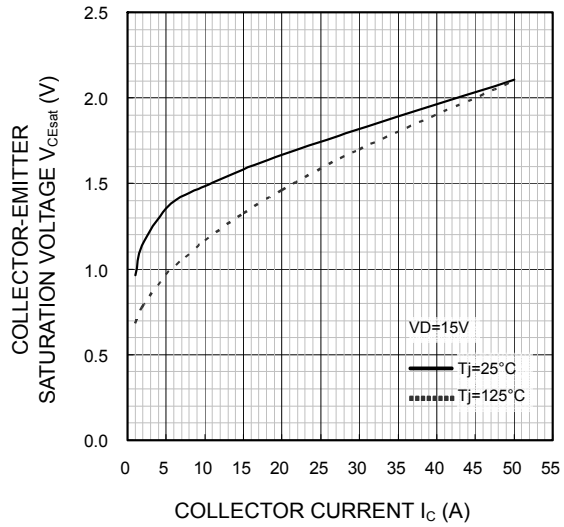


**PERFORMANCE CURVES**

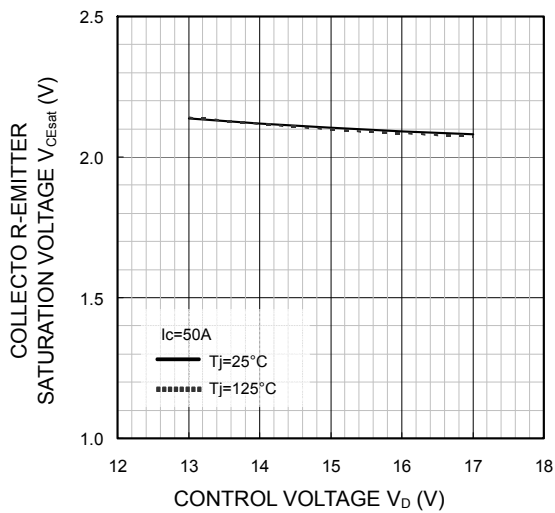
**OUTPUT CHARACTERISTICS**



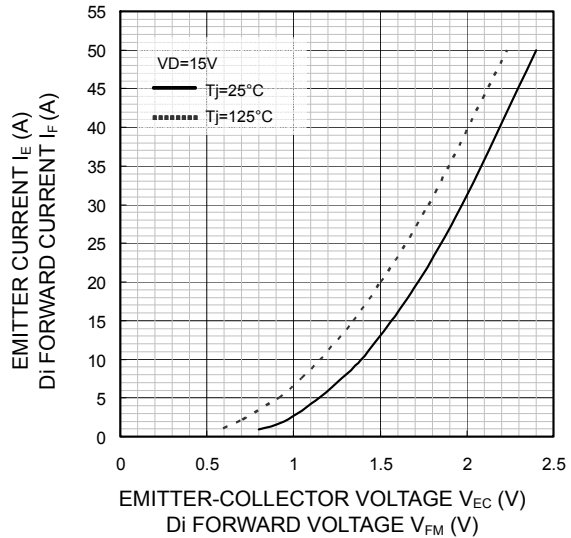
**COLLECTOR-EMITTER SATURATION VOLTAGE (VS.  $I_c$ ) CHARACTERISTICS (TYPICAL)**  
INVERTER PART & CONVERTER PART



**COLLECTOR-EMITTER SATURATION VOLTAGE (VS.  $V_D$ ) CHARACTERISTICS (TYPICAL)**  
INVERTER PART & CONVERTER PART



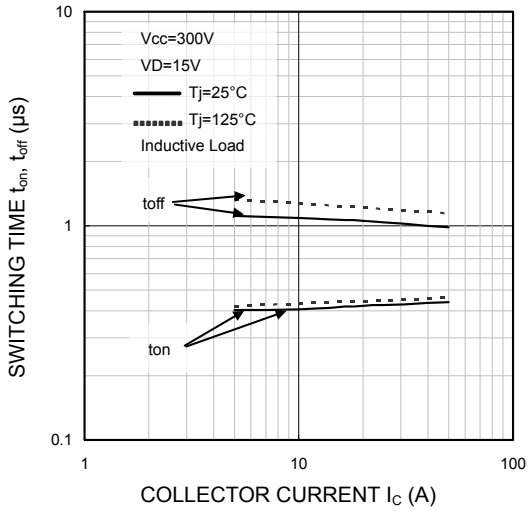
**FREE WHEELING DIODE & DIODE FORWARD CHARACTERISTICS (TYPICAL)**  
INVERTER PART & CONVERTER PART



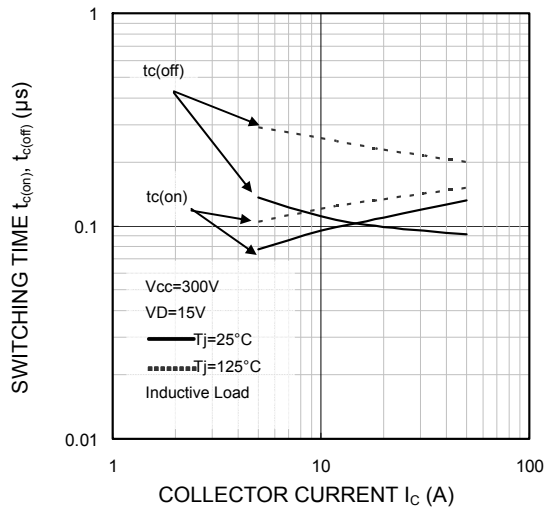
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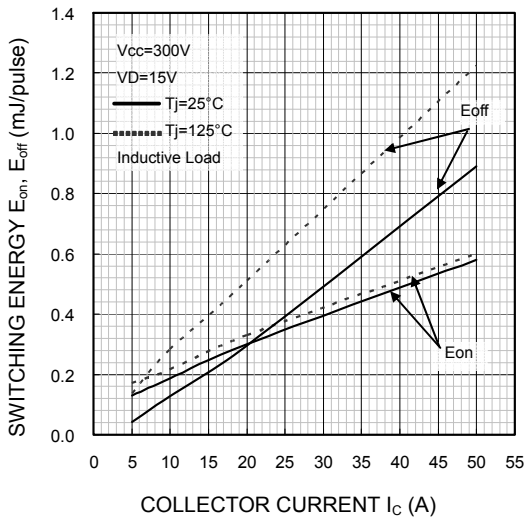
**SWITCHING TIME ( $t_{on}$ ,  $t_{off}$ ) CHARACTERISTICS  
(TYPICAL)  
INVERTER PART & CONVERTER PART**



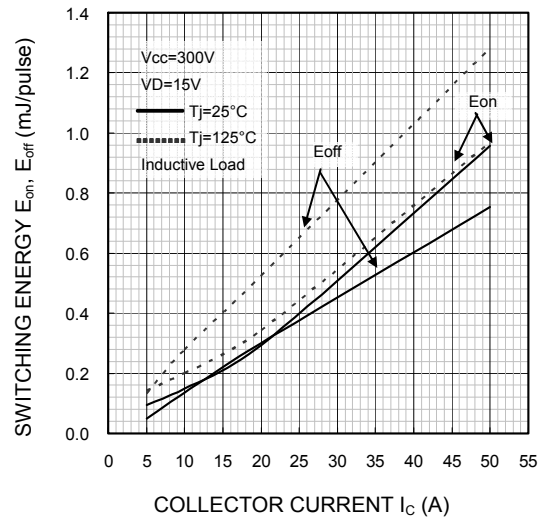
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(TYPICAL)  
INVERTER PART & CONVERTER PART**



**SWITCHING ENERGY CHARACTERISTICS  
(TYPICAL)  
INVERTER PART**



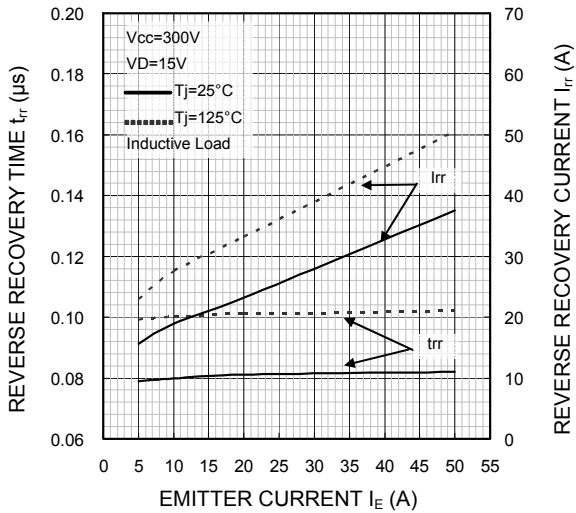
**SWITCHING ENERGY CHARACTERISTICS  
(TYPICAL)  
CONVERTER PART**



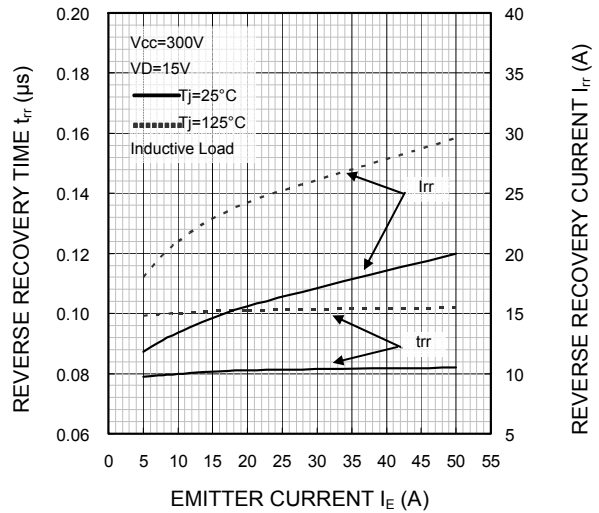
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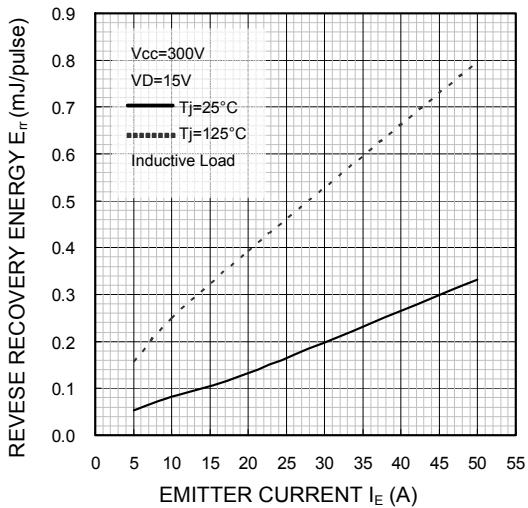
FREE WHEELING DIODE  
REVERSE RECOVERY CHARACTERISTICS  
(TYPICAL)  
INVERTER PART



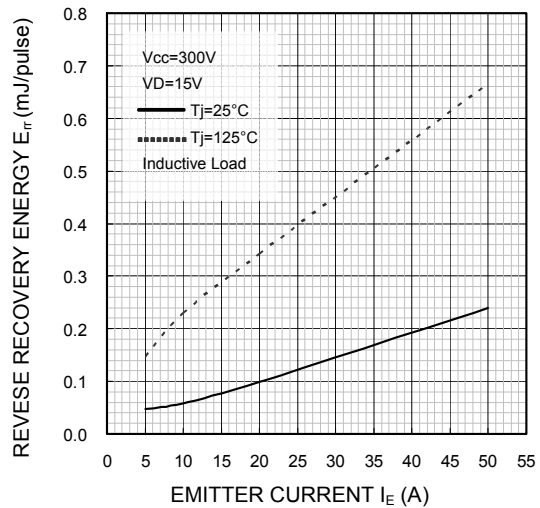
FREE WHEELING DIODE  
REVERSE RECOVERY CHARACTERISTICS  
(TYPICAL)  
CONVERTER PART



FREE WHEELING DIODE  
REVERSE RECOVERY ENERGY  
CHARACTERISTICS  
(TYPICAL)  
INVERTER PART



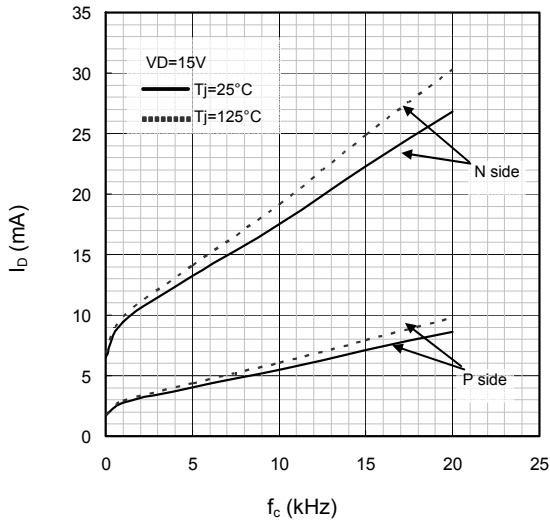
FREE WHEELING DIODE  
REVERSE RECOVERY ENERGY  
CHARACTERISTICS  
(TYPICAL)  
CONVERTER PART



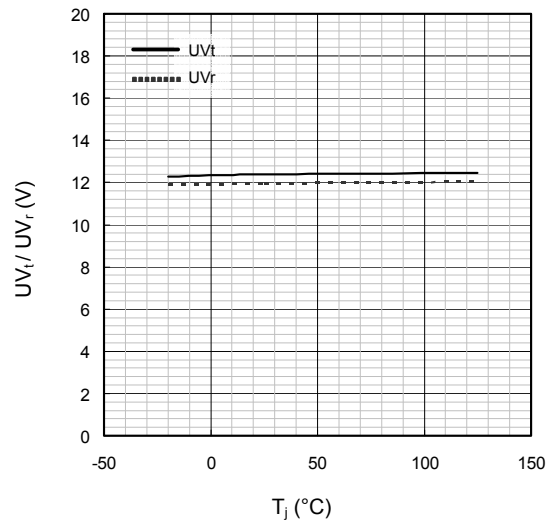
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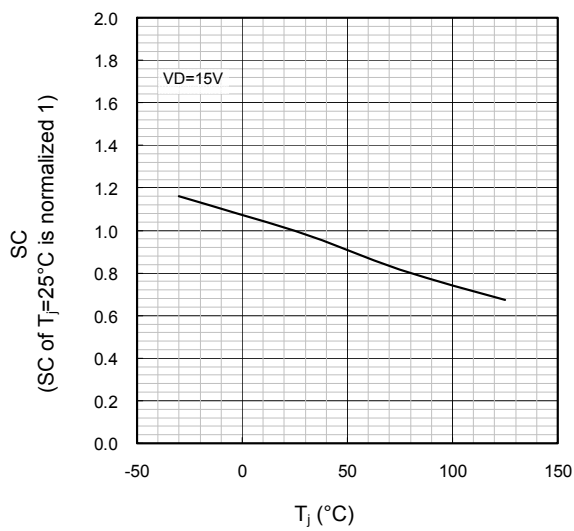
**I<sub>D</sub> VS. f<sub>c</sub> CHARACTERISTICS  
(TYPICAL)**



**UV TRIP LEVEL VS. T<sub>j</sub> CHARACTERISTICS  
(TYPICAL)**



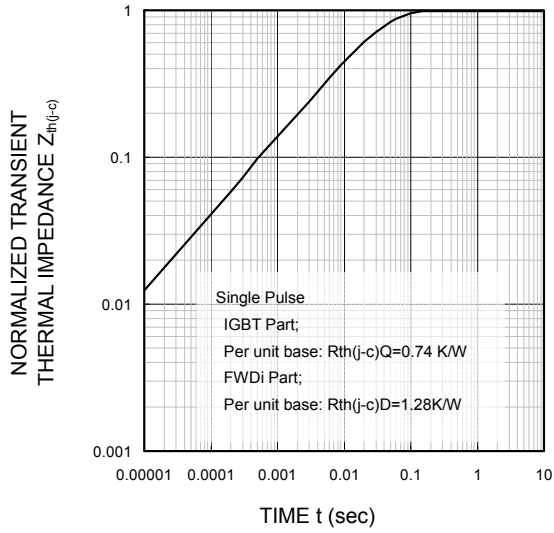
**SC TRIP LEVEL VS. T<sub>j</sub> CHARACTERISTICS  
(TYPICAL)  
INVERTER PART & CONVERTER PART**



**PM50B5L1C060**

**FLAT-BASE TYPE  
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**TRANSIENT THERMAL  
IMPEDANCE CHARACTERISTICS  
INVERTER PART**



**TRANSIENT THERMAL  
IMPEDANCE CHARACTERISTICS  
CONVERTER PART**

